

3.3 V and 5 V High Speed Transistor Optocouplers FOD050L, FOD053L

Description

The FOD050L and FOD053L optocouplers consist of an AlGaAs LED optically coupled to a high speed photodetector transistor. These devices are specified for operation at 3.3 V and 5 V supply voltages.

A separate connection for the bias of the photodiode improves the speed by several orders of magnitude over conventional phototransistor optocouplers by reducing the base-collector capacitance of the input transistor.

An internal noise shield provides superior common mode rejection of $CM_H = 50 \text{ kV/µs}$ (typical) and $CM_L = 35 \text{ kV/µs}$ (typical).

Features

- Low Power Consumption
- High Speed
- Available in Single-Channel 8-Pin SOIC (FOD050L) or Dual-Channel 8-Pin SOIC (FOD053L)
- Superior CMR CM_H = $50 \text{ kV/}\mu\text{s}$ (typical) and CM_L = $35 \text{ kV/}\mu\text{s}$ (typical)
- Guaranteed Performance over Temperature: 0°C to 70°C
- Safety and Regulatory Approvals:
 - ◆ UL1577, 2,500 VAC_{RMS} for 1 Minute
 - ◆ DIN-EN/IEC60747-5-5, 565 V Peak Working Insulation Voltage

Applications

- Line Receivers
- Pulse Transformer Replacement
- High-Speed Logic Ground Isolation: LVTTL/LVCMOS
- Wide Bandwidth Analog Coupling

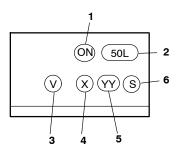
TRUTH TABLE

LED	v _o
On	LOW
Off	HIGH



SOIC8 CASE 751DZ

MARKING DIAGRAM



- 1. ON = onsemi Logo
- 2. 50L = Device Number (50L or 53L)
- 3. V = DIN EN/IEC60747-5-5 Option (only appears on component with this option
 - X = One-Digit Year Code, e.g. '5'
- 5. YY = Two Digit Work Week, Ranging from '01' to '53'
- 6. S = Assembly Package Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 10 of this data sheet.

Schematics

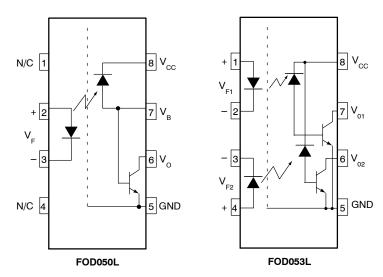


Figure 1. Schematics

SAFETY AND INSULATION RATINGS

As per DIN EN/IEC 60747–5–5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

Parameter	Characteristics	
Installation Classification per DIN VDE 0110/1.89 Table 1,	< 150 V _{RMS}	I–IV
For Rated Mains Voltage	< 300 V _{RMS}	I-III
Climatic Classification	55/100/21	
Pollution Degree (DIN VDE 0110/1.89)	2	
Comparative Tracking Index	175	

Symbol	Parameter	Value	Unit
V _{PR}	Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10$ s, Partial Discharge < 5 pC	904	Vpeak
	Input-to-Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ s, Partial Discharge < 5 pC	1060	Vpeak
V _{IORM}	Maximum Working Insulation Voltage	565	Vpeak
V _{IOTM}	Highest Allowable Over-Voltage	4000	Vpeak
	External Creepage	≥ 4	mm
	External Clearance	≥ 4	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥ 0.4	mm
Ts	Case Temperature (Note 1)	150	°C
I _{S,INPUT}	Input Current (Note 1)	200	mA
P _{S,OUTPUT}	Output Power (Note 1)	300	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V (Note 1)	> 10 ⁹	Ω

^{1.} Safety limit values – maximum values allowed in the event of a failure.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Value	Unit	
T _{STG}	Storage Temperature	-40 to +125	°C	
T _{OPR}	Operating Temperature		-40 to +85	°C
TJ	Junction Temperature		-40 to +125	°C
T _{SOL}	Lead Solder Temperature		260 for 10 seconds	°C
EMITTER				•
I _F (avg)	DC/Average Forward Input Current	Each Channel	25	mA
I _F (pk)	Peak Forward Input Current (50% duty cycle, 1 ms P.W.)	Each Channel	50	mA
I _F (trans)	Peak Transient Input Current (≤1 μs P.W., 300 pps)	Each Channel	1.0	Α
V_R	Reverse Input Voltage	Each Channel	5	V
P _D	Input Power Dissipation (No derating required up to 85°C) Each Channel		45	mW
DETECTOR				
I _O (avg)	Average Output Current	Each Channel	8	mA
I _O (pk)	Peak Output Current	Each Channel	16	mA
V _{EBR}	Emitter-Base Reverse Voltage	FOD050L only	5	V
V _{CC}	Supply Voltage		-0.5 to 7	V
Vo	Output Voltage		-0.5 to 7	V
I _B	Base Current	FOD050L only	5	mA
P _D	Output Power Dissipation (No derating required up to 85°C)	Each Channel	100	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS

($T_A = 0^{\circ}C$ to $70^{\circ}C$, unless otherwise specified.)

INDIVIDUAL COMPONENT CHARACTERISTICS

Symbol	Parameter	Test Conditions	Device	Min.	Тур.	Max.	Unit
EMITTER				•			•
V_{F}	Input Forward Voltage	I _F = 16 mA, T _A = 25°C	All		1.45	1.7	V
٧F	Input i ofward voltage	I _F = 16 mA	All			1.8	V
B_VR	Input Reverse Breakdown Voltage	reakdown I _R = 10 μA		5.0			V
DETECTOR	R			•	•		•
I _{OH}	Logic High Output Current	$I_F = 0$ mA, $V_O = V_{CC} = 3.3$ V & 5 V, $T_A = 25^{\circ}C$	All		0.001	1	μΑ
I _{CCL}	Logic Low Supply Current	$I_F = 16 \text{ mA}, V_O = \text{Open}, V_{CC} = 3.3 \text{ V } \& 5 \text{ V}$	FOD050L			200	μΑ
		$I_{F1} = I_{F2} = 16$ mA, $V_{O} = Open$, $V_{CC} = 3.3$ V & 5 V	FOD053L			400	
I _{CCH}	Logic High Supply Current	$I_F = 0$ mA, $V_O = Open$, $V_{CC} = 3.3$ V & 5 V, $T_A = 25$ °C	FOD050L			0.3	μΑ
		$I_F = 0$ mA, $V_O = Open$, $V_{CC} = 3.3 \text{ V & 5 V}$	FOD053L			10	

TRANSFER CHARACTERISTICS

Symbol	Parameter	Test Conditions	Device	Min.	Тур.	Max.	Unit
COUPLED							
CTR	Current Transfer Ratio (Note 2)	I_F = 16 mA, V_O = 0.4 V, V_{CC} = 3.3 V & 5 V, T_A = 25°C	All	15		50	%
V _{OL}	Logic Low Output Voltage	I_F = 16 mA, I_O = 3 mA, V_{CC} = 3.3 V & 5 V, T_A = 25°C	All			0.3	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Current Transfer Ratio is defined as a ratio of output collector current, I_O, to the forward LED input current, I_F, times 100%.

ELECTRICAL CHARACTERISTICS (Continued)

 $(T_A = 0^{\circ}C \text{ to } 70^{\circ}C, \text{ unless otherwise specified.})$

SWITCHING CHARACTERISTICS (V_{CC} = 3.3 V & 5 V)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
_	Propagation Delay Time to	$R_L = 1.9 \text{ k}\Omega$, $I_F = 16 \text{ mA (Note 3)}$	25°C			1.0	
T _{PHL}	Logic LOW	(Figure 10)				2.0	μS
T _{PLH}	Propagation Delay Time to	$R_L = 1.9 \text{ k}\Omega$, $I_F = 16 \text{ mA (Note 3)}$	25°C			1.0	
	Logic HIGH					2.0	μS
CM _H	Common Mode Transient Immunity at Logic HIGH	I_F = 0 mA, V_{CM} = 1,000 V_{P-P} , R_L = 4.1 kΩ, T_A = 25°C (Notes 4, 5) (Figure 11)		5,000	50,000		V/μs
		I_F = 0 mA, V_{CM} = 1,000 V_{P-P} , R_L = 1.9 kΩ, T_A = 25°C (Notes 3, 5) (Figure 11)		5,000	50,000		V/μs
CM _L	Common Mode Transient Immunity at Logic LOW	I_F = 16 mA, V_{CM} = 1,000 V_{P-P} , R_L = 4.1 kΩ, T_A = 25°C (Notes 4, 5) (Figure 11)		5,000	35,000		V/μs
		$\label{eq:loss_problem} \begin{split} I_{F} = 16 \text{ mA, } V_{CM} = \text{1,000 } V_{P-P}, R_{L} = \text{1.9 k}\Omega, \\ \text{(Notes 3, 5) (Figure 11)} \end{split}$	T _A = 25°C	5,000	35,000		V/μs

ISOLATION CHARACTERISTICS

Symbol	Characteristics	Test Conditions	Min.	Тур.	Max.	Unit
I _{I-O}	Imbul-Outbul insulation Leakage Current	Relative humidity = 45%, $T_A = 25$ °C, t = 5 s, V_{I-O} = 3000 VDC (Note 6)			1.0	μΑ
V _{ISO}	Withstand Insulation Test Voltage	f = 60 Hz, T _A = 25°C, t = 60 s (Note 6)	2500			V _{RMS}
R _{I-O}	Resistance (Input to Output)	V _{I-O} = 500 VDC (Note 6)	10 ¹¹	10 ¹²		Ω
C _{I-O}	Capacitance (Input to Output)	f = 1 MHz (Note 6)		0.2		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 3. The 1.9 k Ω load represents 1 TTL unit load of 1.6 mA and 5.6 k Ω pull-up resistor.
- 4. The 4.1 k Ω load represents 1 LSTTL unit load of 0.36 mA and 6.1 k Ω pull-up resistor.
- 5. Common mode transient immunity in logic high level is the maximum tolerable (positive) dV_{cm}/dt on the leading edge of the common mode pulse signal V_{CM}, to assure that the output will remain in a logic high state (i.e., V_O > 2.0 V). Common mode transient immunity in logic low level is the maximum tolerable (negative) dV_{cm}/dt on the trailing edge of the common mode pulse signal, V_{CM}, to assure that the output will remain in a logic low state (i.e., V_O < 0.8 V).</p>
- 6. Device is considered a two terminal device: pins 1, 2, 3 and 4 are shorted together and pins 5, 6, 7 and 8 are shorted together.

TYPICAL PERFORMANCE CURVES

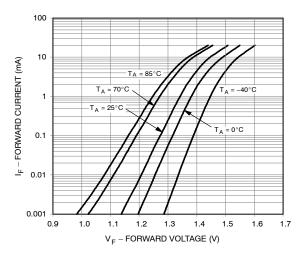


Figure 2. LED Forward Current vs. Forward Voltage

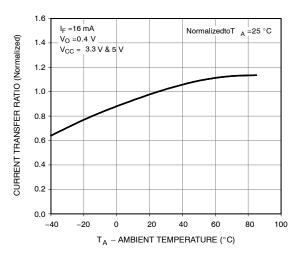


Figure 4. Current Transfer Ratio vs. Ambient Temperature

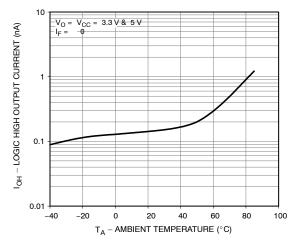


Figure 6. Logic High Output Current vs. Ambient Temperature

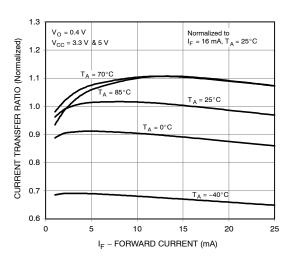


Figure 3. Current Transfer Ratio vs. Forward Current

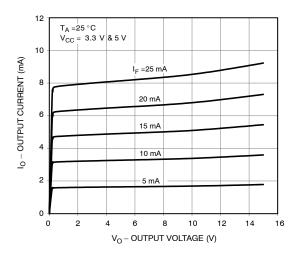


Figure 5. Output Current vs. Output Voltage

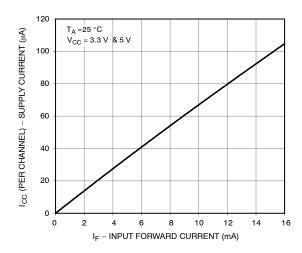
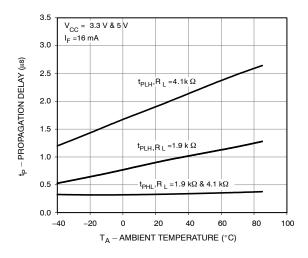


Figure 7. Supply Current vs. Input Forward Current

TYPICAL PERFORMANCE CURVES (Continued)



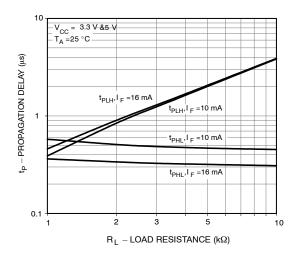


Figure 8. Propagation Delay vs. Ambient Temperature

Figure 9. Propagation Delay vs. Load Resistance

TEST CIRCUITS

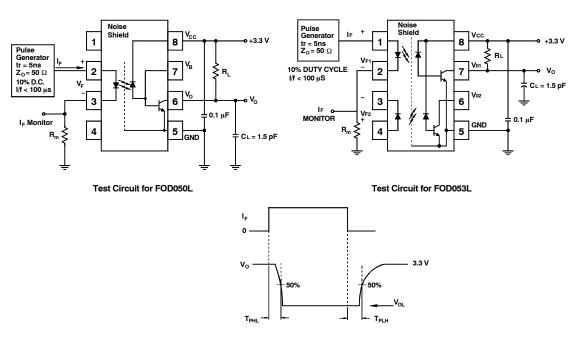


Figure 10. Switching Time Test Circuit

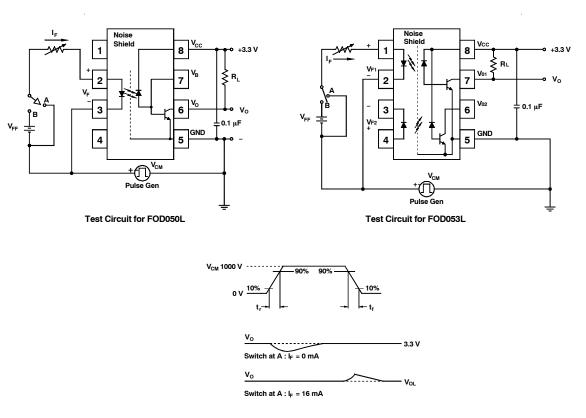


Figure 11. Common Mode Immunity Test Circuit

REFLOW PROFILE

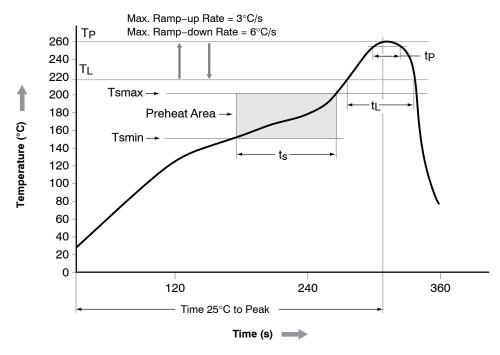


Figure 12. Reflow Profile

Profile Freature	Pb-Free Assembly Profile
Temperature Minimum (Tsmin)	150°C
Temperature Maximum (Tsmax)	200°C
Time (t _S) from (Tsmin to Tsmax)	60 – 120 s
Ramp-up Rate (t _L to t _P)	3°C/s max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 s
Peak Body Package Temperature	260°C + 0°C / -5°C
Time (t _P) within 5°C of 260°C	30 s
Ramp-down Rate (T _P to T _L)	6°C/s max.
Time 25°C to Peak Temperature	8 minutes max.

ORDERING INFORMATION

Part Number (Note 7)	Package	Packing Method [†]
FOD050L	SOIC8 (Pb-Free)	Tube (50 Units per Tube)
FOD050LR2	SOIC8 (Pb-Free)	Tape and Reel (1000 Units per Reel)
FOD050LV	SOIC8 (Pb-Free), DIN EN/IEC60747-5-5 Option	Tube (50 Units per Tube)
FOD050LR2V	SOIC8 (Pb-Free), DIN EN/IEC60747-5-5 Option	Tape and Reel (1000 Units per Reel)

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

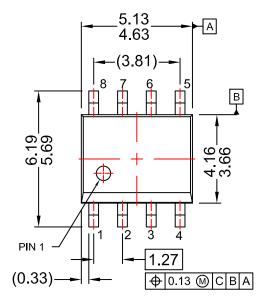
7. The product orderable part number system listed in this table also applies to the FOD053L product.

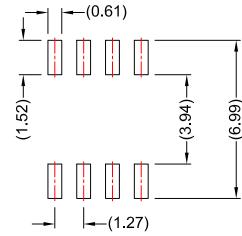
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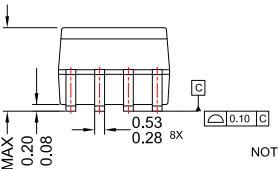
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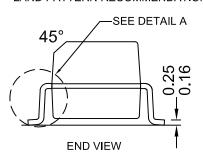
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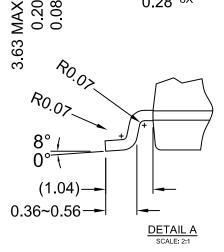
LAND PATTERN RECOMMENDATION





NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS.
- D) LANDPATTERN STANDARD: SOIC127P600X175-8M.



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